
HD74BC541A

Octal Buffers/Line Drivers With 3 State Outputs

HITACHI

ADE-205-023 (Z)

Rev. 0

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Description

The HD74BC541A provides high drivability and operation equal to or better than high speed bipolar standard logic IC by using Bi-CMOS process. The device features low power dissipation that is about 1/5 of high speed bipolar logic IC, when the frequency is 10 MHz. The device has eight inverter drivers with three state outputs in a 20 pin package. When $\overline{G1}$ and $\overline{G2}$ is low level, this drivers set up output is enable.

Features

- Input/Output are at high impedance state when power supply is off.
- Built in input pull up circuit can make input pins be open, when not used.
- Input is TTL level.
- Wide operating temperature range
 $T_a = -40$ to $+85^{\circ}\text{C}$

Function Table

Inputs

$\overline{G1}$	$\overline{G2}$	A	Output Y
L	L	L	L
L	L	H	H
H	X	X	Z
X	H	X	Z

H : High level

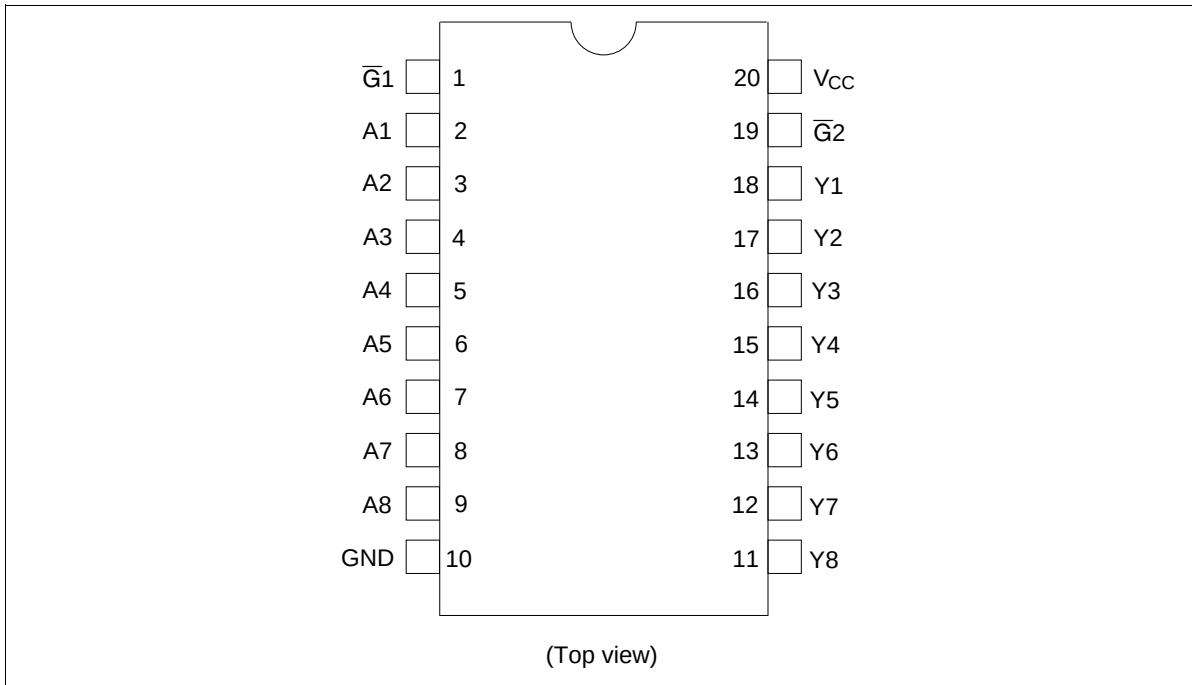
L : Low level

X : Immaterial

Z : High impedance

HD74BC541A

Pin Arrangement



Absolute Maximum Ratings

Item	Symbol	Rating	Unit
Supply voltage	V_{CC}	-0.5 to +7.0	V
Input diode current	I_{IK}	± 30	mA
Input voltage	V_{IN}	-0.5 to +7.5	V
Output voltage	V_{OUT}	-0.5 to +7.5	V
Off state output voltage	$V_{OUT(off)}$	-0.5 to +5.5	V
Storage temperature	Tstg	-65 to +150	°C

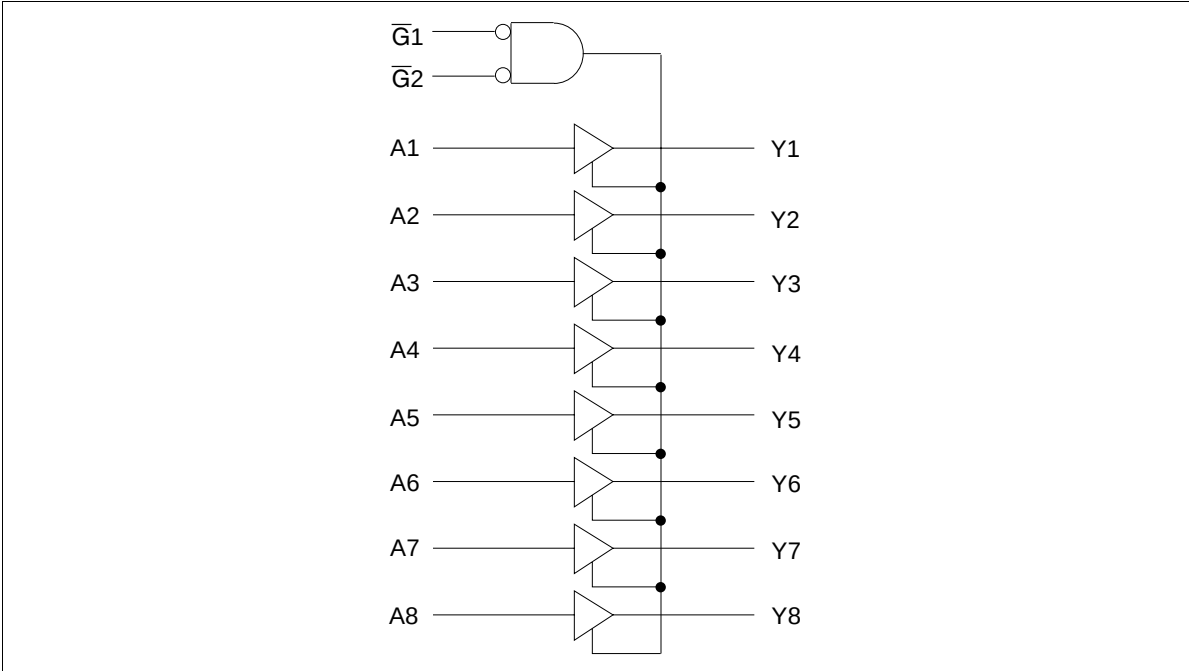
Note: 1. The absolute maximum ratings are values which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

Recommended Operating Conditions

Item	Symbol	Min	Typ	Max	Unit
Supply voltage	V_{CC}	4.5	5.0	5.5	V
Input voltage	V_{IN}	0	—	V_{CC}	V
Ouput voltage	V_{OUT}	0	—	V_{CC}	V
Operating temperature	Topr	−40	—	85	°C
Input rise/fall time*1	t_r, t_f	0	—	8	ns/V

Note: 1. This item guarantees maximum limit when one input switches.
Waveform: Refer to test circuit of switching characteristics.

Logic Diagram



Electrical Characteristics (Ta = -40 to +85°C)

Item	Symbol	V _{cc} (V)	Min	Max	Unit	Test Conditions
Input voltage	V _{IH}		2.0	—	V	
	V ^{IL}		—	0.8	V	
Output voltage	V _{OH}	4.5	2.4	—	V	I _{OH} = -3 mA
		4.5	2.0	—	V	I _{OH} = -15 mA
	V _{OL}	4.5	—	0.5	V	I _{OL} = 48 mA
		4.5	—	0.55	V	I _{OL} = 64 mA
Input diode voltage	V _{IK}	4.5	—	-1.2	V	I _{IN} = -18 mA
Input current	I _I	5.5	—	-250	μA	V _{IN} = 0 V
		5.5	—	1.0	μA	V _{IN} = 5.5 V
		5.5	—	100	μA	V _{IN} = 7.0 V
Short circuit output current*1	I _{OS}	5.5	-100	-225	mA	V _{IN} = 0 or 5.5 V
Off state output current	I _{OZH}	5.5	—	50	μA	V _O = 2.7 V
	I _{OZL}	5.5	—	-50	μA	V _O = 0.5 V
Supply current	I _{CCL}	5.5	—	29.5	mA	V _{IN} = V _{CC} or GND All outputs is "L"
	I _{CCH}	5.5	—	0.5	mA	V _{IN} = V _{CC} or GND All outputs is "H"
	I _{CCZ}	5.5	—	2.5	mA	V _{IN} = V _{CC} or GND All outputs is "Z"
	I _{CCT} *2	5.5	—	1.5	mA	V _{IN} = 3.4V or 0.5V

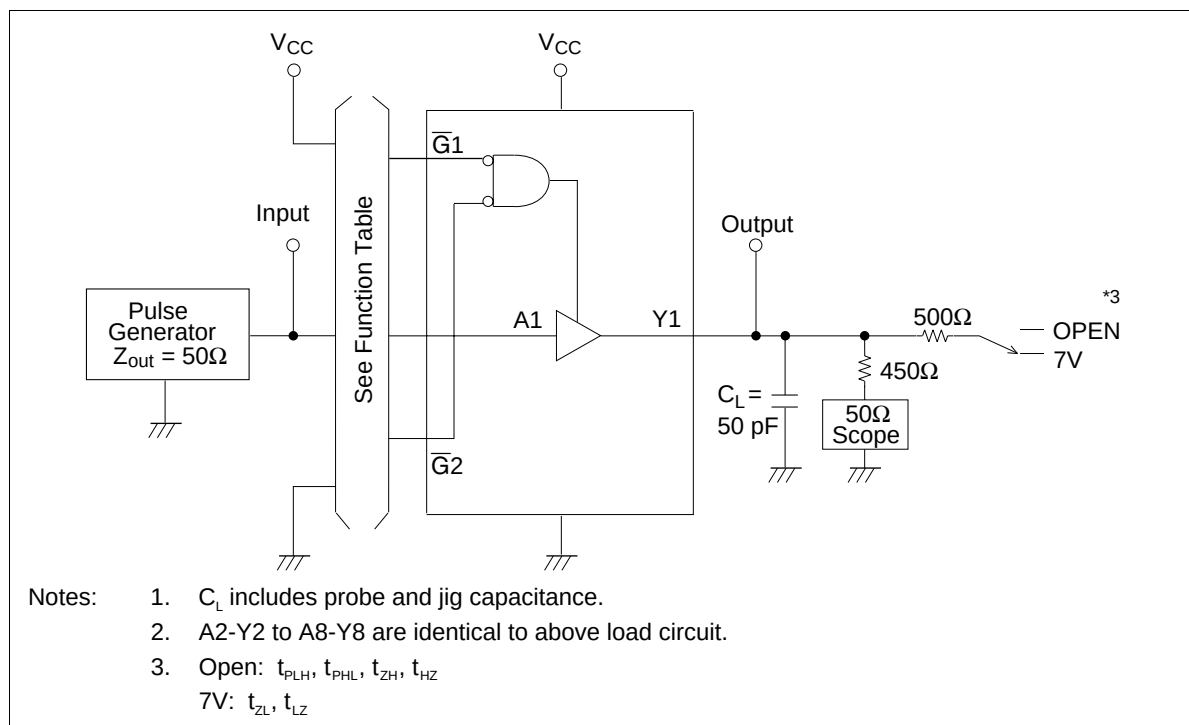
Notes: 1. Not more than one output should be shorted at a time and duration of the short circuit should not exceed one second.

2. When input by the TTL level, it shows I_{CC} increase at per one input pin.

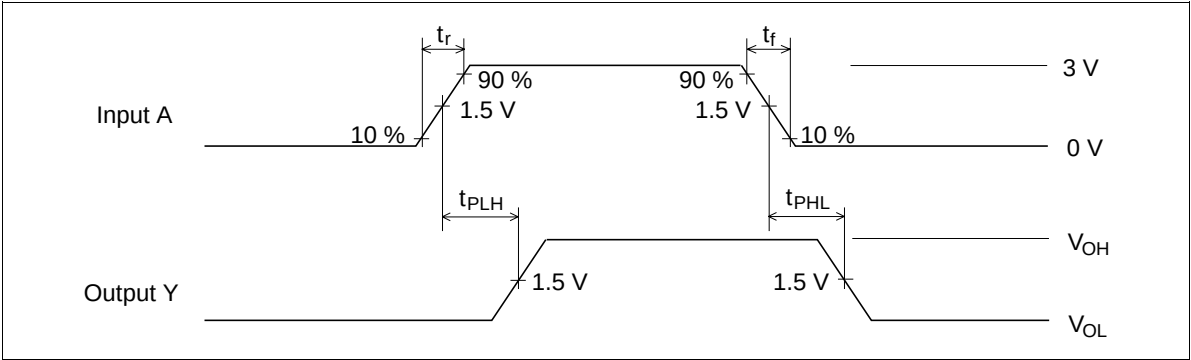
Switching Characteristics (C_L = 50 pF)

Item	Symbol	Ta = 25°C V _{CC} = 5.0 V		Ta = -40 to +85°C V _{CC} = 5.0 V ±10%		Unit	Test Conditions
		Min	Max	Min	Max		
Propagation delay time	t _{PLH}	3.0	6.0	3.0	7.0	ns	See under figure
	t _{PHL}	3.0	6.0	3.0	7.0		
Output enable time	t _{ZH}	3.0	9.0	3.0	11.0	ns	
	t _{ZL}	3.0	9.0	3.0	11.0		
Output disable time	t _{HZ}	3.0	8.0	3.0	10.0	ns	
	t _{LZ}	3.0	8.0	3.0	10.0		
Input capacitance	C _{IN}	3.0 (Typ)		—		pF	V _{IN} = V _{CC} or GND
Output capacitance	C _O	15.0 (Typ)		—		pF	V _O = V _{CC} or GND

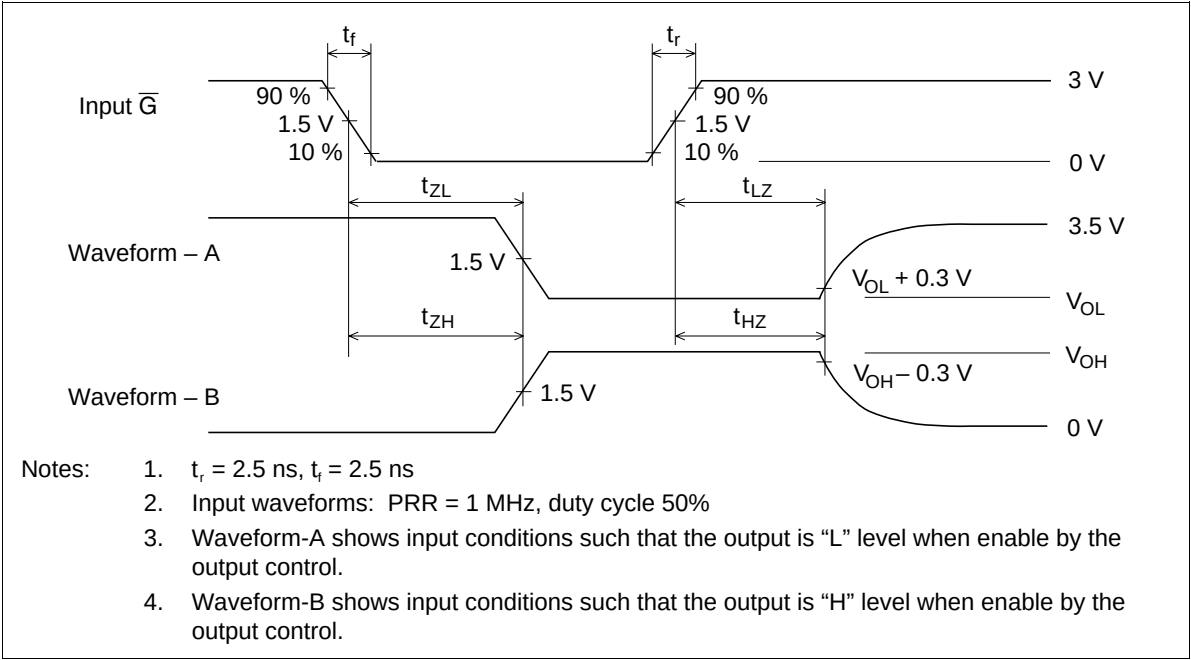
Test circuit



Waveforms-1



Waveforms-2



Package Dimensions

Unit: mm

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HITACHI

Hitachi, Ltd.

Semiconductor & Integrated Circuits.
Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan
Tel: Tokyo (03) 3270-2111 Fax: (03) 3270-5109

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For further information write to:

Hitachi Semiconductor (America) Inc. 179 East Tasman Drive, San Jose, CA 95134 Tel: <1> (408) 433-1990 Fax: <1> (408) 433-0223	Hitachi Europe GmbH Electronic components Group Dornacher Straße 3 D-85622 Feldkirchen, Munich Germany Tel: <49> (89) 9 9180-0 Fax: <49> (89) 9 29 30 00 Hitachi Europe Ltd. Electronic Components Group. Whitebrook Park Lower Cookham Road Maidenhead Berkshire SL6 8YA, United Kingdom Tel: <44> (1628) 585000 Fax: <44> (1628) 778322
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Hitachi Asia Pte. Ltd. 16 Collyer Quay #20-00 Hitachi Tower Singapore 049318 Tel: 535-2100 Fax: 535-1533 Hitachi Asia Ltd. Taipei Branch Office 3F, Hung Kuo Building. No.167, Tun-Hwa North Road, Taipei (105) Tel: <886> (2) 2718-3666 Fax: <886> (2) 2718-8180
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Hitachi Asia (Hong Kong) Ltd. Group III (Electronic Components) 7/F., North Tower, World Finance Centre, Harbour City, Canton Road, Tsim Sha Tsui, Kowloon, Hong Kong Tel: <852> (2) 735 9218 Fax: <852> (2) 730 0281 Telex: 40815 HITEC HX
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